

Silanna Ultraviolet Light Emitting Diodes

2022



Introduction to Silanna

- Privately funded 2006
- Semiconductor technology focus
- From research through development to commercialisation
- History
 - 2006 Silanna formed to develop and commercialise high performance, non-volatile memory
 - 2008 Sydney wafer fab acquired from Peregrine Semiconductor Corporation
 - 2010 New Fab commissioned with Molecular Beam Epitaxy
 - 2020 Commence construction of new global Headquarters building from Pinkenba, Brisbane



Beyond Innovation



- 2014 –Sponsored Caterham F1 Team
- 2015-2018 Sponsored Sauber F1 Team



Foundry

Incubation of new technology businesses

(from concept to commercial success)

RF Industry leading RF switches (on SOI) – Acquired by Qualcomm

Isolation World's first high speed USB 2.0 isolators (on SOS)

Power Industry leading power switches (on SOI)

High voltage power switches

Substrates High thermal conductivity substrates

UV emitters Industry leading UVC Light Emitting Diodes

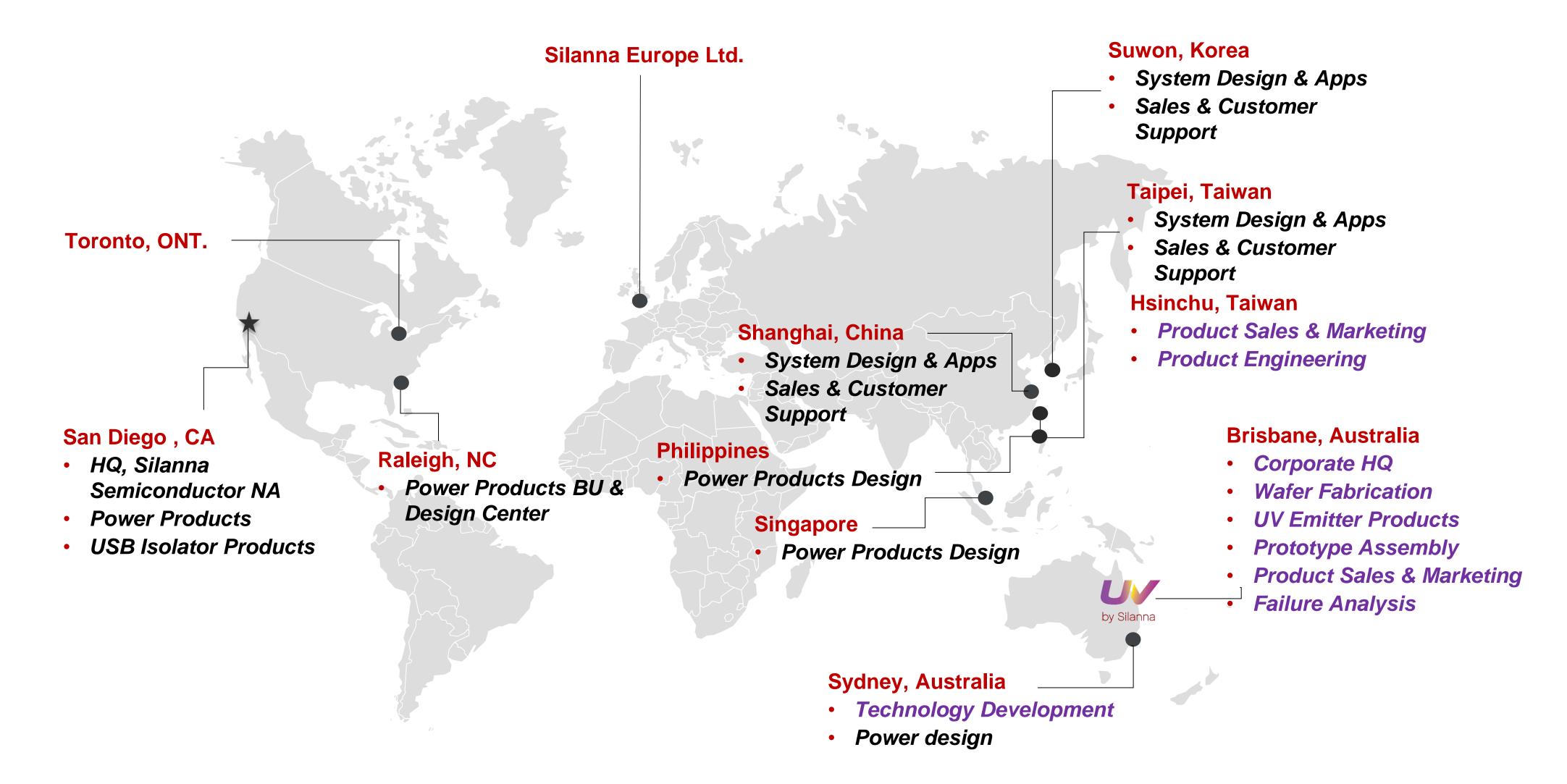
Prototyping and production on SOS, SOI, etc

Silanna Revolutionizing UV Technology





Silanna Locations





Silanna's facility

- Situated on a 15,000 m² Brisbane riverfront site in Pinkenba, Brisbane
- 100mm compound semiconductor epitaxy production fab, with 925m² class 100-10,000 cleanrooms
- Research lab in Adelaide

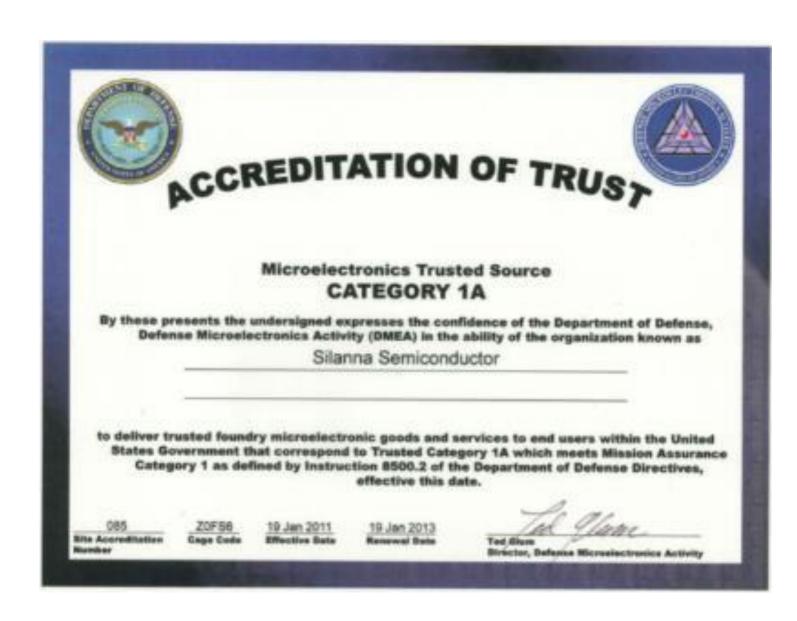


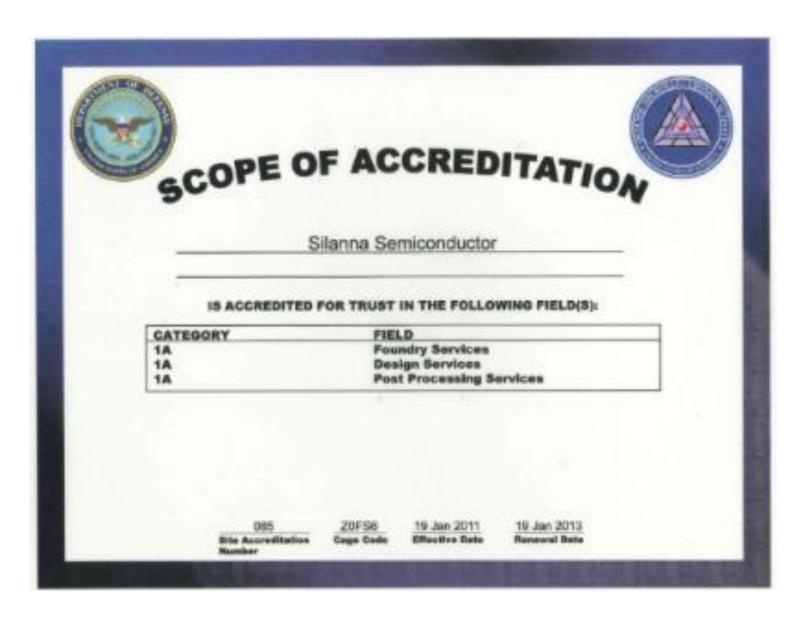




Accreditations

- ISO 9001:2015 LRQA certification
- US Defence MicroElectronic Activity (DMEA) Trusted Foundry clearance to "secret" level





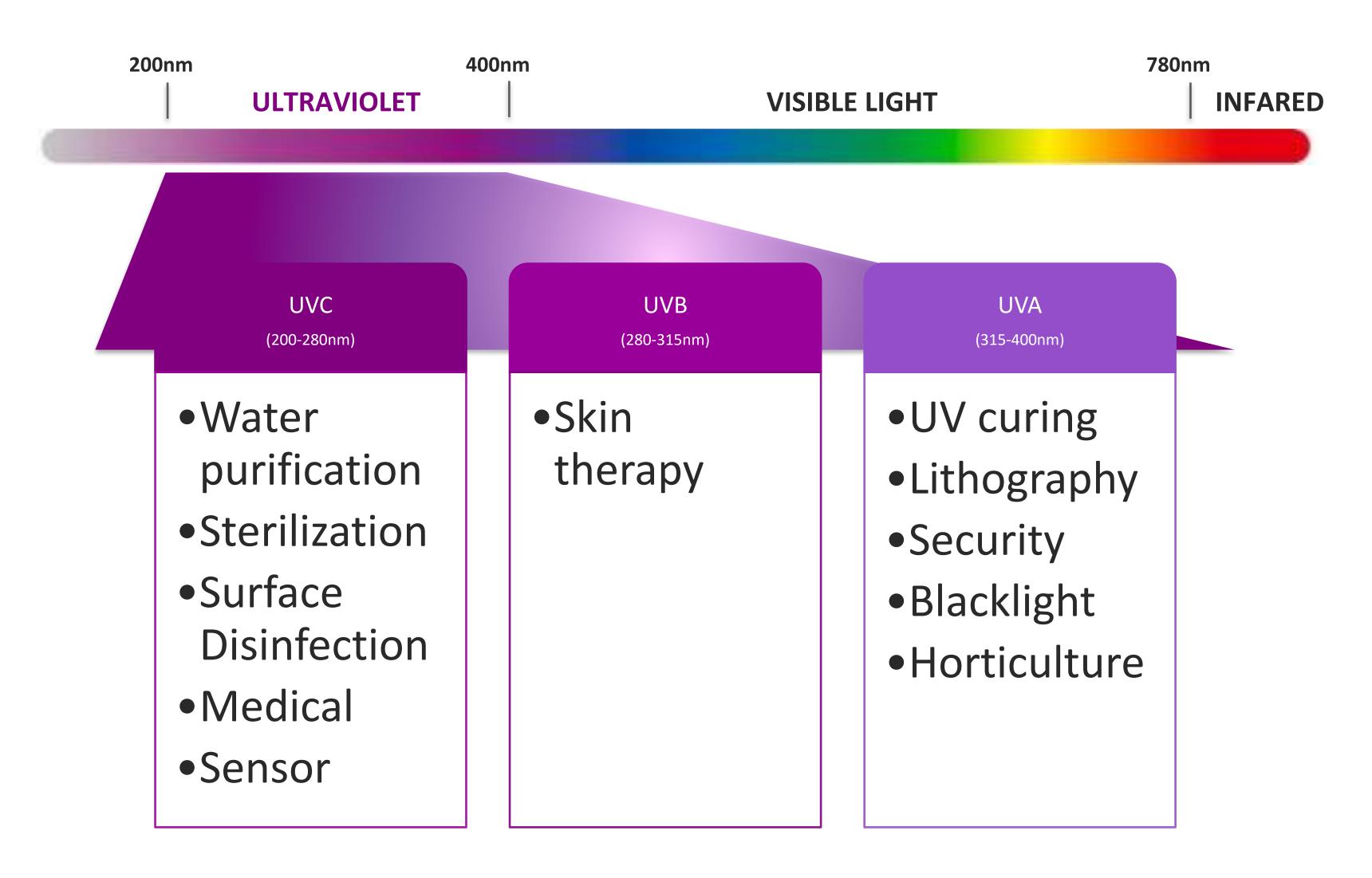




Silanna UVC LEDs

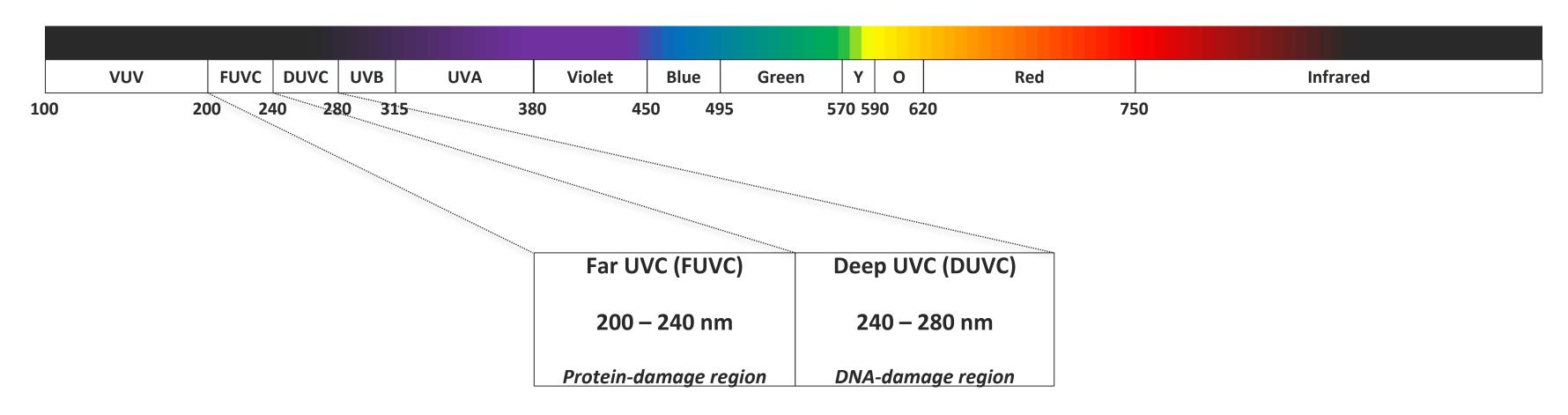


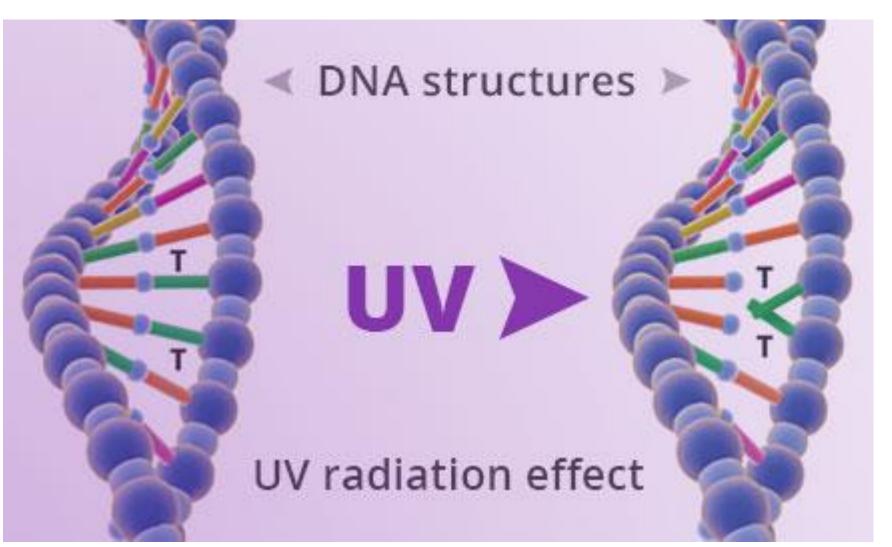
UV wavelength definition





More than just UVC

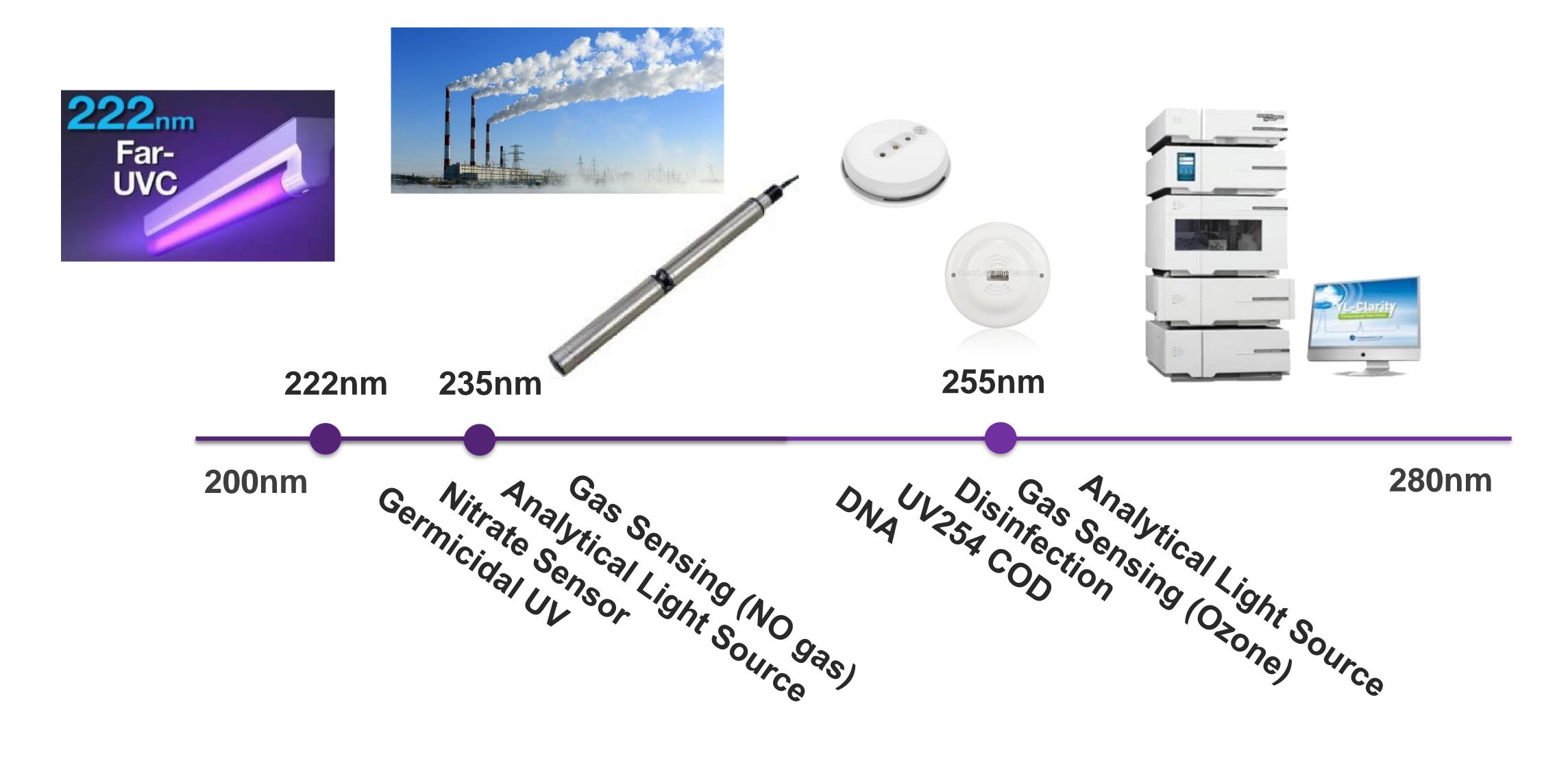




With sufficient dose, UVC light will deactivate any microbe (virus, bacteria, protozoa, mold, fungus, etc.)



Near UVC & Far UVC LED applications





DUVC & FUVC Light source Comparison

Light source Type	Deuterium lamp	Xenon flash lamp	LED Solution
Wavelength	185-400nm	185 to 2000nm	235nm/255nm
Power consumption	30W	2W	0.12W
Warm-up Time	20 second +	Instant	Instant
Typ. Lifetime (L50)	1,000hrs	1 X 10 ⁹	L50 2,000hrs /L50 10,000hrs
Module	Yes	Yes	Option
Lamp Cost (USD)	\$400~\$700	\$700~900	Lower
Photo			Silanna Silanna Dual Setter Centent Current





Features

- Deep Ultraviolet LED
- Small Footprint
- ESD protection
- Mercury Free

Applications including

- Water quality monitoring
- Gas Sensing
- Liquid Chromatography
- Chemical and biological analysis

13

Disinfection



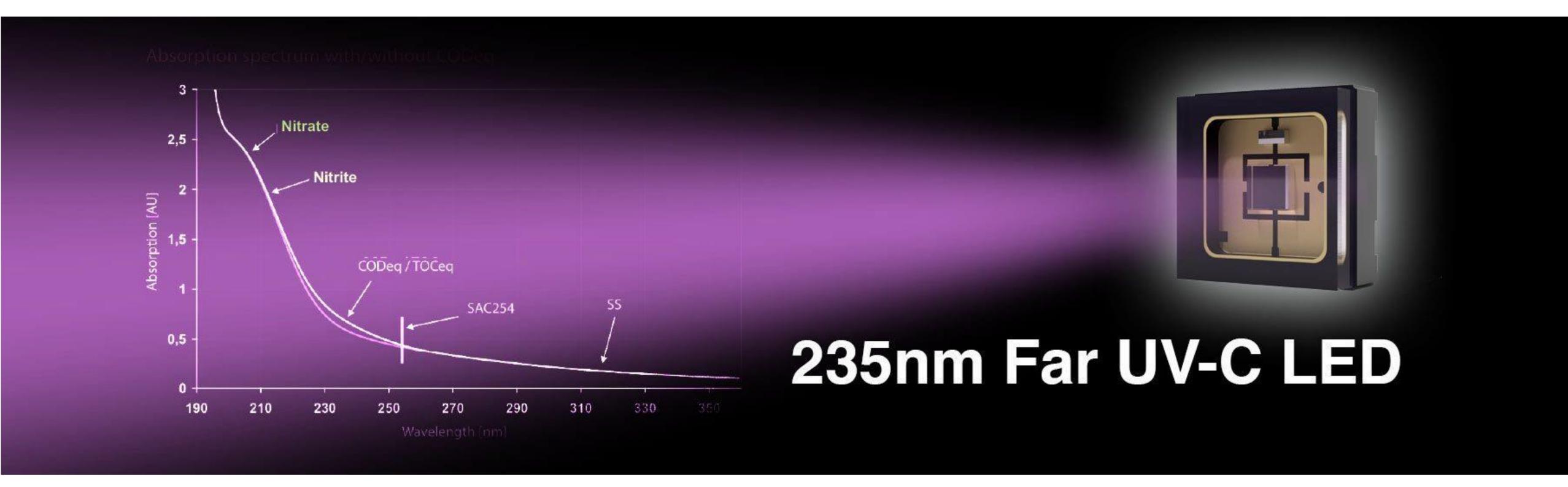
SN3 255nm LED characteristics

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Peak wavelength	λ	250	255	260	nm	1, 2
FWHM	FWHM	-	12	18	nm	1
Radiant flux	Роит	0.5	0.8	-	mW	1, 3
Forward voltage	V	5	-	7	V	1, 4
Viewing angle	degree	-	120	-		1
Power dissipation	P_{D}	-	0.12	-	W	1

Test conditions:

- 1. $T = 25^{\circ}$ C ambient, $T_{\text{solder point}} = 25^{\circ}$ C with Peltier controlled heatsink, Forward Current = 20mA, 10ms integration time
- 2. Wavelength measurement accuracy is ±2.0 nm
- 3. Radiant flux measurement accuracy is ±10%
- 4. Forward voltage accuracy is ±0.2 V





Features

- Far Ultraviolet LED
- Small Footprint
- ESD protection
- Mercury Free

Applications including

- Water quality monitoring
- Gas Sensing
- Liquid Chromatography
- Chemical and biological analysis
- Disinfection



SF1 235nm LED characteristics

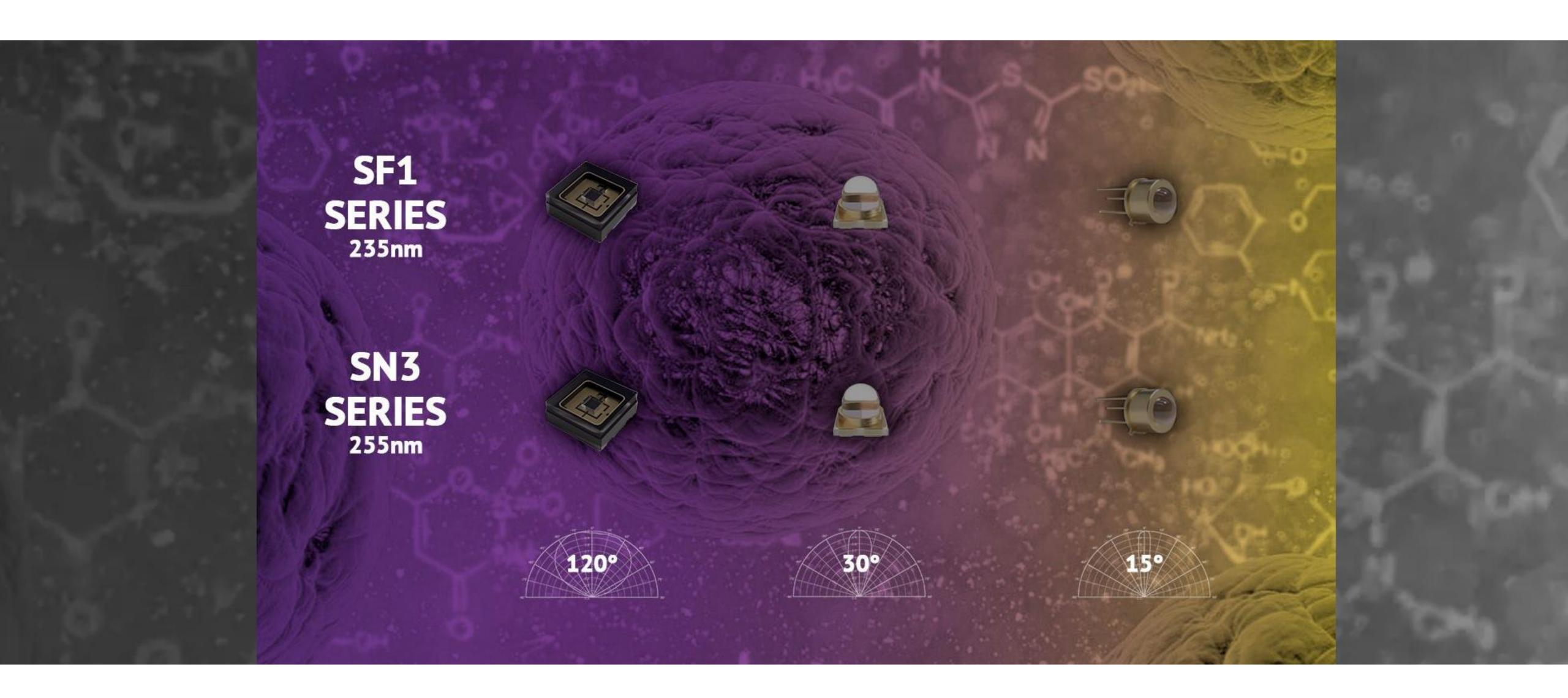
Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Peak wavelength	λ	230	235	240	nm	1, 2
FWHM	FWHM	5	10	15	nm	1
Radiant flux	Роит	0.05	0.5	-	mW	1, 3
Forward voltage	V	6	7	8	V	1, 4
Viewing angle	degree	-	120	-		1
Power dissipation	P_{D}	-	0.14	-	W	1

Test conditions:

- 1. T = 25°C ambient, Tsolder point = 25°C with Peltier controlled heatsink, Forward Current = 20mA, 10ms integration time
- 2. Wavelength measurement accuracy is ±2.0 nm
- 3. Radiant flux measurement accuracy is ±10%
- 4. Forward voltage accuracy is ±0.2 V









Thank you

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